Spontaneous Formation of Stress Domains on Crystal S

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1	Origins of stress on elemental and chemisorbed semiconductor surfaces. Physical Review Letters, 1989, 63, 1404-1407.	2.9	170
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18	Finite-temperature phase diagram of vicinal Si(100) surfaces. Physical Review Letters, 1990, 64, 2406-2409.	2.9	315

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36	Growth Properties of the Si(100) Steps: A Molecular Dynamics Study. Materials Research Society Symposia Proceedings, 1991, 237, 217.	0.1	0

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